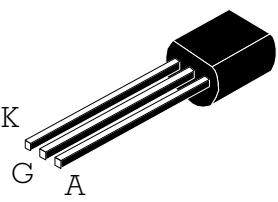
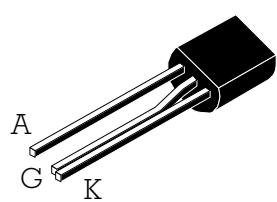


SENSITIVE GATE SCR

TO92 (Plastic)	RD26 (Plastic)	On-State Current 1.25 Amp		Gate Trigger Current < 200 μ A	
 FS02...A	 FS02...B	Off-State Voltage 200V ÷ 800V			
These series of Silicon C ontrolled R ectifier use a high performance PNPN technology. These parts are intended for general purpose applications where high gate sensitivity is required.					

Absolute Maximum Ratings, according to IEC publication No. 134

SYMBOL	PARAMETER	CONDITIONS	Min.	Max.	Unit
$I_{T(RMS)}$	On-state Current	All Conduction Angle, $T_L = 60^\circ C$	1.25		A
$I_{T(AV)}$	Average On-state Current	Half Cycle, $\alpha = 180^\circ, T_L = 60^\circ C$	0.8		A
I_{TSM}	Non-repetitive On-State Current	Half Cycle, 60 Hz, $T_j = 25^\circ C$	25		A
I_{TSM}	Non-repetitive On-State Current	Half Cycle, 50 Hz, $T_j = 25^\circ C$	22.5		A
I^2t	Fusing Current	$t_p = 10ms$, Half Cycle	2.5		A^2s
V_{GRM}	Peak Reverse Gate Voltage	$I_{GR} = 10 \mu A, T_j = 25^\circ C$	8		V
I_{GM}	Peak Gate Current	20 μs max.		1.2	A
P_{GM}	Peak Gate Dissipation	20 μs max.		3	W
$P_{G(AV)}$	Gate Dissipation	20ms max.		0.2	W
T_j	Operating Temperature		-40	+125	$^\circ C$
T_{stg}	Storage Temperature		-40	+150	$^\circ C$
T_{sld}	Soldering Temperature	1.6 mm from case, 10s max.		260	$^\circ C$

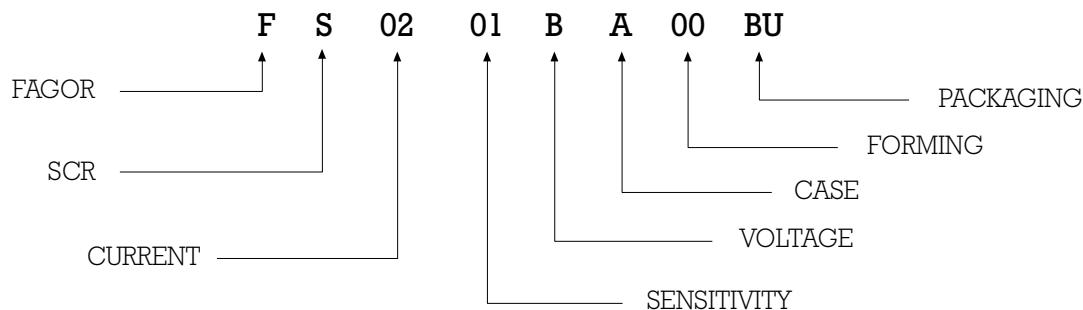
SYMBOL	PARAMETER	CONDITIONS	VOLTAGE				Unit
			B	D	M	N	
V_{DRM}	Repetitive Peak Off State Voltage	$R_{GK} = 1 K$	200	400	600	800	V
V_{RRM}							

SENSITIVE GATE SCR

Electrical Characteristics

SYMBOL	PARAMETER	CONDITIONS	SENSITIVITY				Unit
			01	04	02	03	
I_{GT}	Gate Trigger Current	$V_D = 12 \text{ V}_{DC}$, $R_L = 140 \Omega$, $T_j = 25^\circ\text{C}$	MIN MAX	1 20	15 50	200 200	μA
I_{DRM} / I_{RRM}	Off-State Leakage Current	$V_D = V_{DRM}$, $R_{GK} = 1\text{K}$, $T_j = 125^\circ\text{C}$ $V_R = V_{RRM}$, $T_j = 25^\circ\text{C}$	MAX MAX		500 5		μA
V_{TM}	On-state Voltage	at $I_T = 1.6 \text{ Amp}$, $t_p = 380 \mu\text{s}$, $T_j = 25^\circ\text{C}$	MAX		1.45		V
$V_{T(O)}$	On-state Threshold Voltage	$T_j = 125^\circ\text{C}$	MAX		0.9		V
r_d	Dinamic Resistance	$T_j = 125^\circ\text{C}$	MAX		200		m
V_{GT}	Gate Trigger Voltage	$V_D = 12 \text{ V}_{DC}$, $R_L = 140 \Omega$, $T_j = 25^\circ\text{C}$	MAX		0.8		V
V_{GD}	Gate Non Trigger Voltage	$V_D = V_{DRM}$, $R_L = 3.3\text{K}$, $R_{GK} = 1\text{K}$, $T_j = 125^\circ\text{C}$	MIN		0.1		V
I_H	Holding Current	$I_T = 50 \text{ mA}$, $R_{GK} = 1\text{K}$, $T_j = 25^\circ\text{C}$	MAX		5		mA
I_L	Latching Current	$I_G = 1 \text{ mA}$, $R_{GK} = 1\text{K}$, $T_j = 25^\circ\text{C}$	MAX		6		mA
dv / dt	Critical Rate of Voltage Rise	$V_D = 0.67 \times V_{DRM}$, $R_{GK} = 1\text{K}$, $T_j = 125^\circ\text{C}$	MIN	15	15	10	20
di / dt	Critical Rate of Current Rise	$I_G = 2 \times I_{GT}$, $T_r = 100 \text{ ns}$, $F = 60 \text{ Hz}$, $T_j = 125^\circ\text{C}$	MIN		50		A/ μs
$R_{th(j-l)}$	Thermal Resistance Junction-Leads for DC				60		$^\circ\text{C/W}$
$R_{th(j-a)}$	Thermal Resistance Junction-Ambient				150		$^\circ\text{C/W}$

PART NUMBER INFORMATION



SENSITIVE GATE SCR

Fig. 1: Maximum average power dissipation versus average on-state current

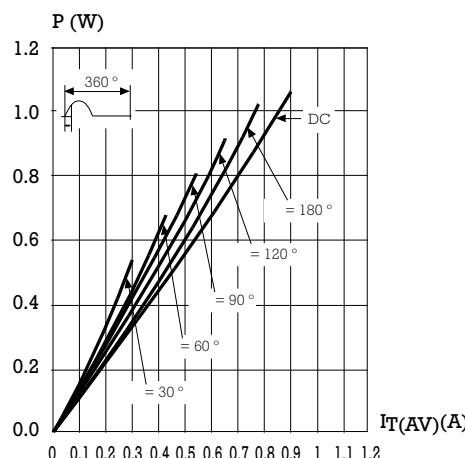


Fig. 3: Average on-state current versus lead temperature

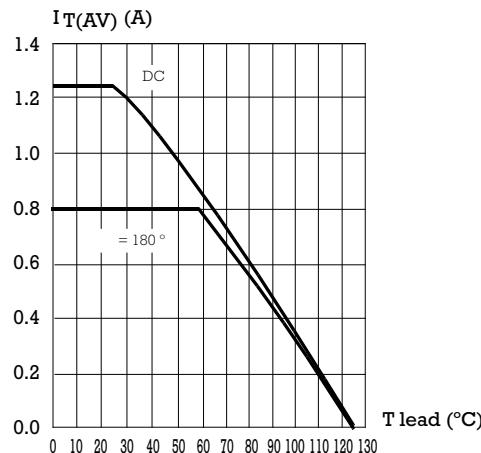


Fig. 5: Relative variation of gate trigger current and holding current versus junction temperature.

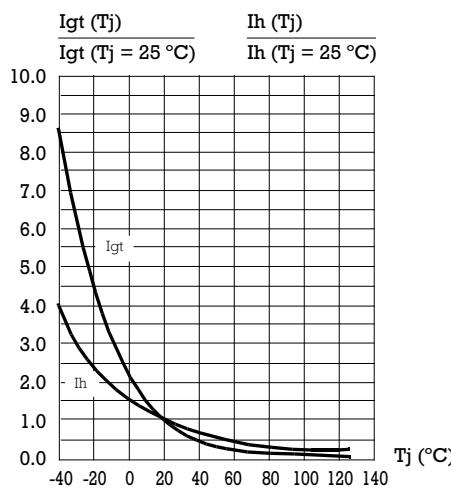


Fig. 2: Correlation between maximum average power dissipation and maximum allowable temperature (Tamb and Tlead).

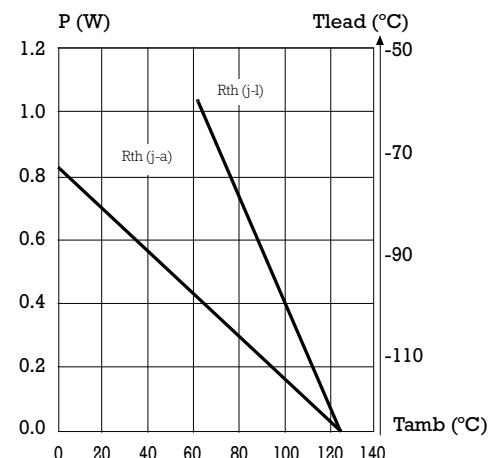


Fig. 4: Relative variation of thermal impedance junction to ambient versus pulse duration.

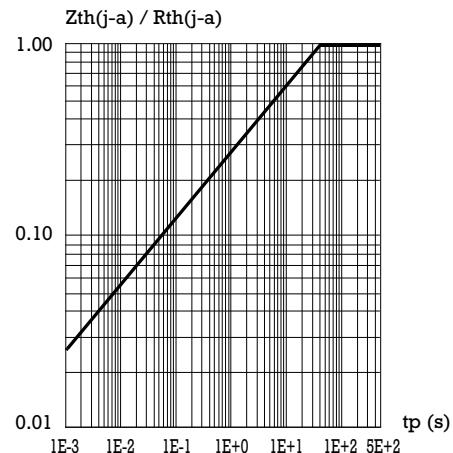
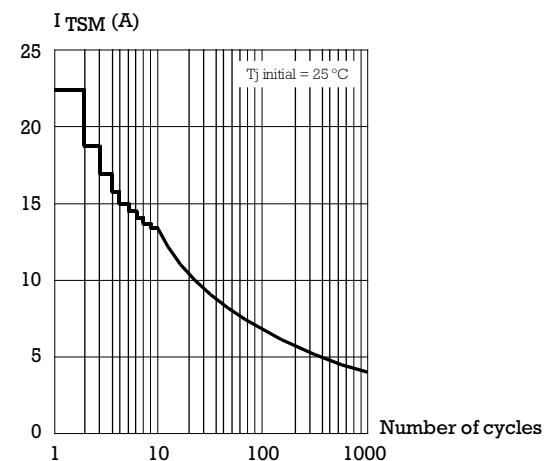


Fig. 6: Non repetitive surge peak on-state current versus number of cycles.



SENSITIVE GATE SCR

Fig. 7: Non repetitive surge peak on-state current for a sinusoidal pulse with width: $t_p = 10 \text{ ms}$, and corresponding value of I^2t .

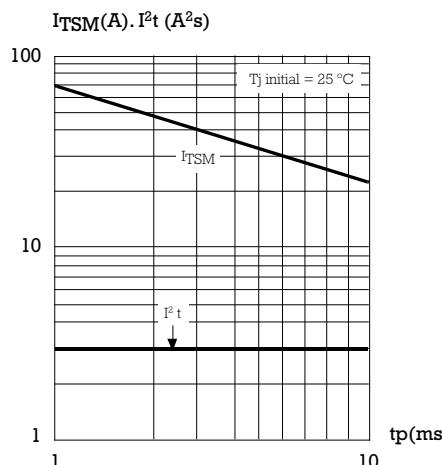
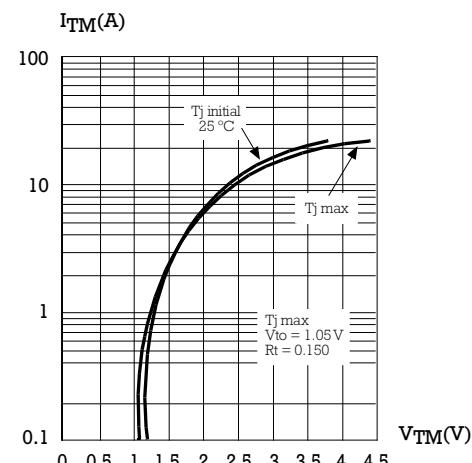


Fig. 8: On-state characteristics (maximum values).



PACKAGE MECHANICAL DATA TO92 (Plastic)

REF.	DIMENSIONS		
	Millimeters		
	Min.	Typ.	Max.
A	-	1.5	-
B	4.55	4.6	4.65
C	2.42	2.54	2.66
D	1.15	1.27	1.39
E	4.55	4.6	4.65
F	12.7	14.1	15.5
G	3.55	3.6	3.65
H	-	1.5	-
a	0.38	0.43	0.48
b	0.33	0.38	0.43

Marking: type number
Weight: 0.2 g

PACKAGE MECHANICAL DATA RD26 (Plastic)

REF.	DIMENSIONS		
	Millimeters		
	Min.	Typ.	Max.
A	-	1.5	-
B	4.55	4.6	4.65
C	2.42	2.54	2.66
D	1.15	1.27	1.39
E	4.55	4.6	4.65
F	12.7	14.1	15.5
G	3.55	3.6	3.65
a	0.38	0.43	0.48
b	0.33	0.38	0.43

Marking: type number
Weight: 0.2 g